

# SKKT 15, SKKH 15



**SEMIPACK® 0**

## Thyristor / Diode Modules

**SKKT 15**

**SKKH 15**

### Features

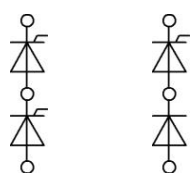
- Heat transfer through aluminium oxide ceramic isolated metal baseplate
- Hard soldered joints for high reliability
- UL recognized, file no. E 63 532

### Typical Applications

- DC motor control (e. g. for machine tools)
- Temperature control (e. g. for ovens, chemical processes)
- Professional light dimming (studios, theaters)

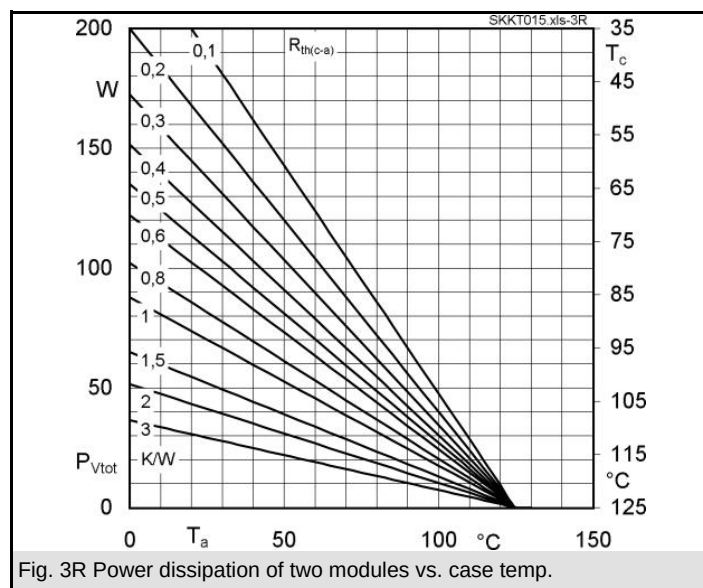
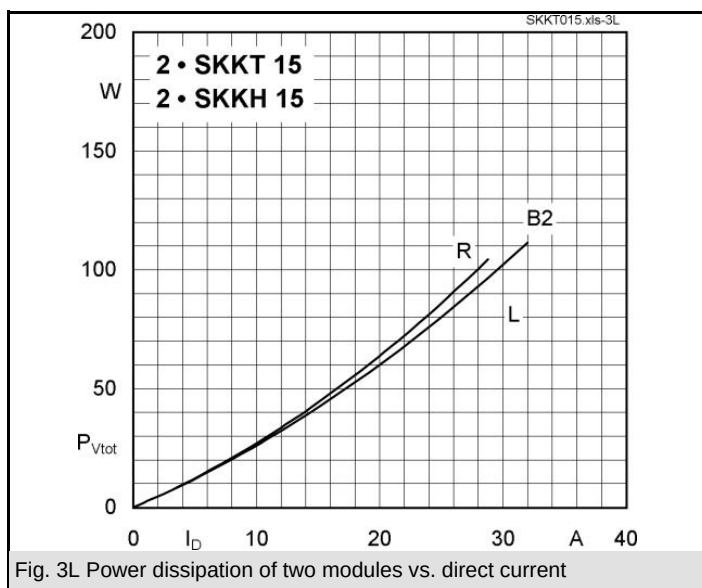
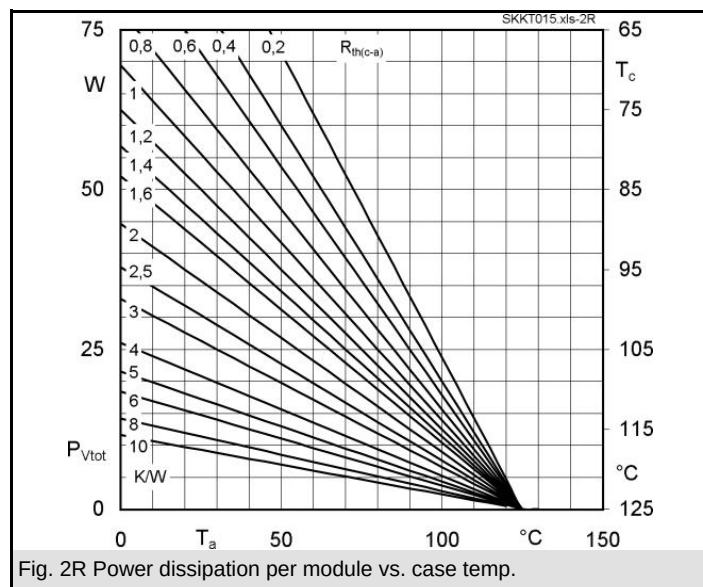
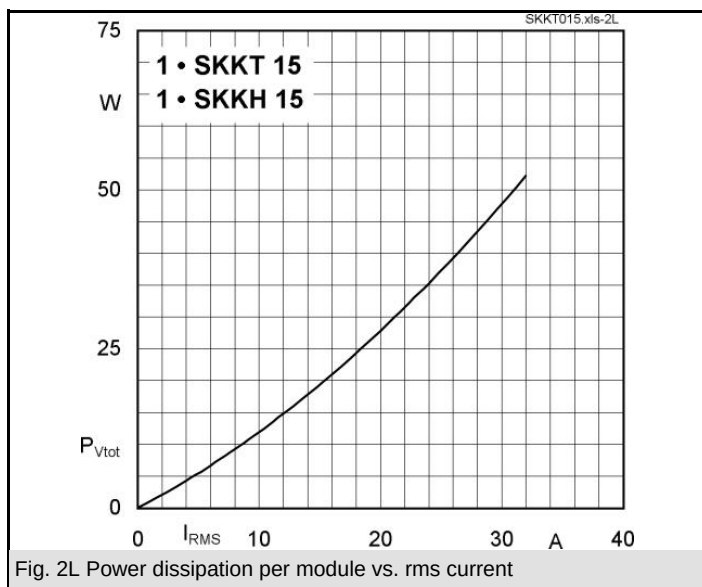
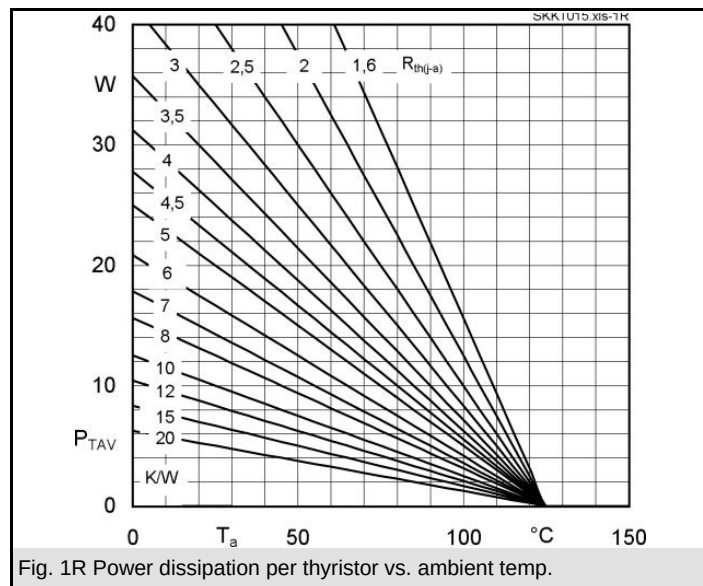
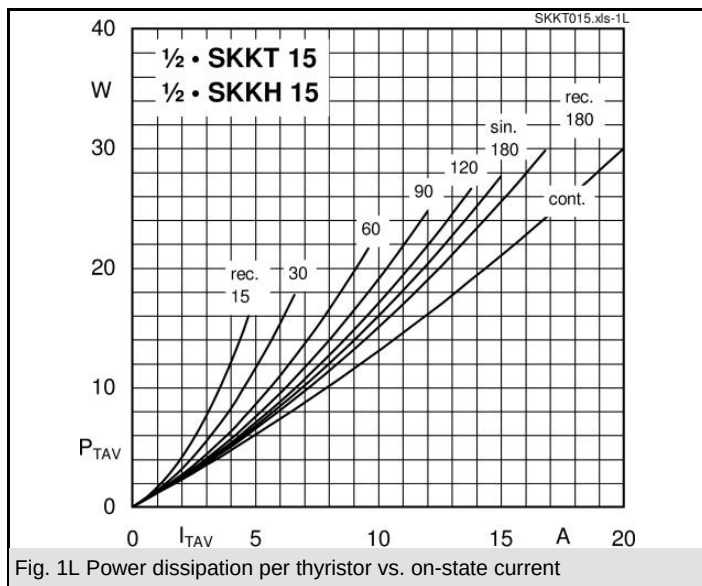
| $V_{RSM}$<br>V | $V_{RRM}, V_{DRM}$<br>V | $I_{TRMS} = 24$ A (maximum value for continuous operation)<br>$I_{TAV} = 15$ A (sin. 180; $T_c = 75$ °C) |             |  |
|----------------|-------------------------|----------------------------------------------------------------------------------------------------------|-------------|--|
| 700            | 600                     | SKKT 15/06E                                                                                              | SKKH 15/06E |  |
| 900            | 800                     | SKKT 15/08E                                                                                              | SKKH 15/08E |  |
| 1300           | 1200                    | SKKT 15/12E                                                                                              | SKKH 15/12E |  |
| 1500           | 1400                    | SKKT 15/14E                                                                                              | SKKH 15/14E |  |
| 1700           | 1600                    | SKKT 15/16E                                                                                              | SKKH 15/16E |  |

| Symbol           | Conditions                                              | Values         | Units |
|------------------|---------------------------------------------------------|----------------|-------|
| $I_{TAV}$        | sin. 180; $T_c = 85$ (100) °C;                          | 13,5 (9,5)     | A     |
| $I_D$            | P13A/100; $T_a = 45$ °C; B2 / B6                        | 14 / 17        | A     |
| $I_{RMS}$        | P13A/100; $T_a = 45$ °C; W1 / W3                        | 21 / 3 x 12    | A     |
| $I_{TSM}$        | $T_{vj} = 25$ °C; 10 ms                                 | 320            | A     |
|                  | $T_{vj} = 125$ °C; 10 ms                                | 280            | A     |
| $i^2t$           | $T_{vj} = 25$ °C; 8,3 ... 10 ms                         | 510            | A²s   |
|                  | $T_{vj} = 125$ °C; 8,3 ... 10 ms                        | 390            | A²s   |
| $V_T$            | $T_{vj} = 25$ °C; $I_T = 75$ A                          | max. 2,45      | V     |
| $V_{T(TO)}$      | $T_{vj} = 125$ °C                                       | max. 1,1       | V     |
| $r_T$            | $T_{vj} = 125$ °C                                       | max. 20        | mΩ    |
| $I_{DD}, I_{RD}$ | $T_{vj} = 125$ °C; $V_{RD} = V_{RRM}, V_{DD} = V_{DRM}$ | max. 8         | mA    |
| $t_{gd}$         | $T_{vj} = 25$ °C; $I_G = 1$ A; $di_G/dt = 1$ A/μs       | 1              | μs    |
| $t_{gr}$         | $V_D = 0,67 * V_{DRM}$                                  | 1              | μs    |
| $(di/dt)_{cr}$   | $T_{vj} = 125$ °C                                       | max. 100       | A/μs  |
| $(dv/dt)_{cr}$   | $T_{vj} = 125$ °C                                       | max. 1000      | V/μs  |
| $t_q$            | $T_{vj} = 125$ °C                                       | 80             | μs    |
| $I_H$            | $T_{vj} = 25$ °C; typ. / max.                           | 80 / 150       | mA    |
| $I_L$            | $T_{vj} = 25$ °C; $R_G = 33$ Ω; typ. / max.             | 150 / 300      | mA    |
| $V_{GT}$         | $T_{vj} = 25$ °C; d.c.                                  | min. 3         | V     |
| $I_{GT}$         | $T_{vj} = 25$ °C; d.c.                                  | min. 100       | mA    |
| $V_{GD}$         | $T_{vj} = 125$ °C; d.c.                                 | max. 0,25      | V     |
| $I_{GD}$         | $T_{vj} = 125$ °C; d.c.                                 | max. 5         | mA    |
| $R_{th(j-c)}$    | cont.; per thyristor / per module                       | 1,6 / 0,8      | K/W   |
| $R_{th(j-c)}$    | sin. 180; per thyristor / per module                    | 1,7 / 0,9      | K/W   |
| $R_{th(j-c)}$    | rec. 120; per thyristor / per module                    | 1,8 / 0,9      | K/W   |
| $R_{th(c-s)}$    | per thyristor / module                                  | 0,2 / 0,1      | K/W   |
| $T_{vj}$         |                                                         | - 40 ... + 125 | °C    |
| $T_{stg}$        |                                                         | - 40 ... + 125 | °C    |
| $V_{isol}$       | a. c. 50 Hz; r.m.s.; 1 s / 1 min.                       | 3600 / 3000    | V~    |
| $M_s$            | to heatsink                                             | 1,5 ± 15 %     | Nm    |
| $a$              |                                                         | 5 * 9,81       | m/s²  |
| $m$              | approx.                                                 | 50             | g     |
| Case             | SKKT                                                    | A 1            |       |
|                  | SKKH                                                    | A 2            |       |

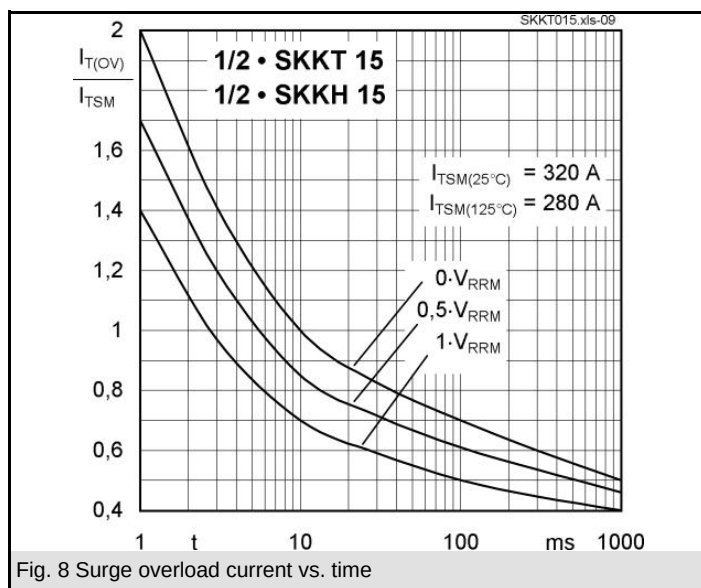
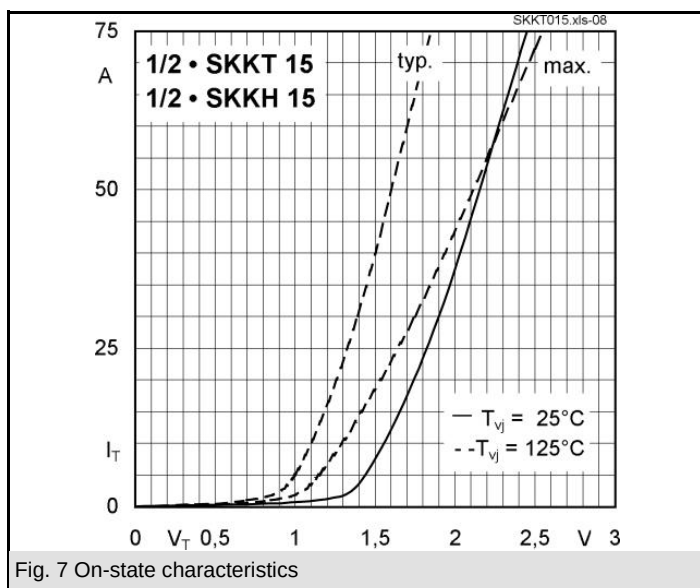
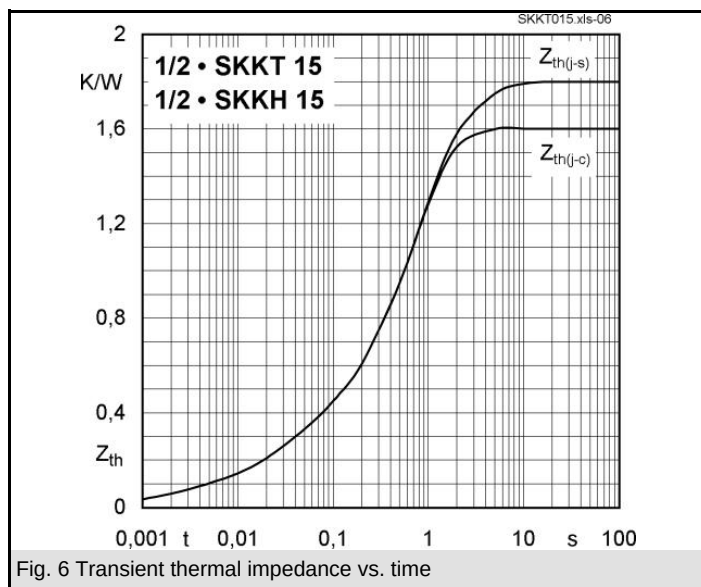
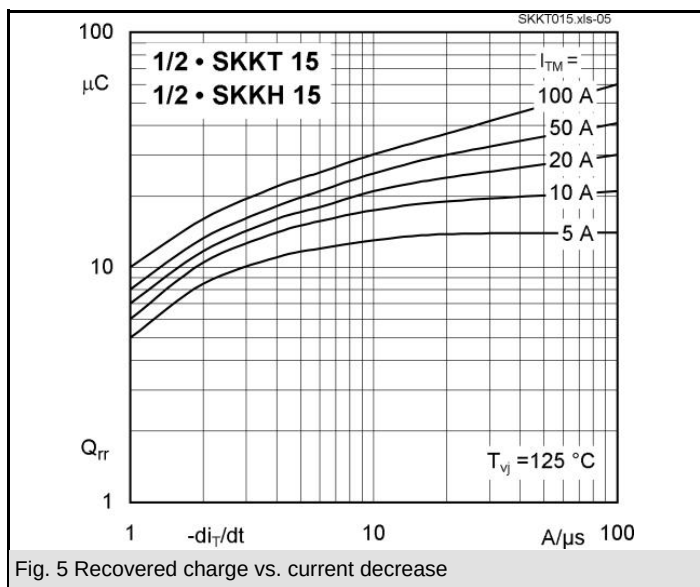
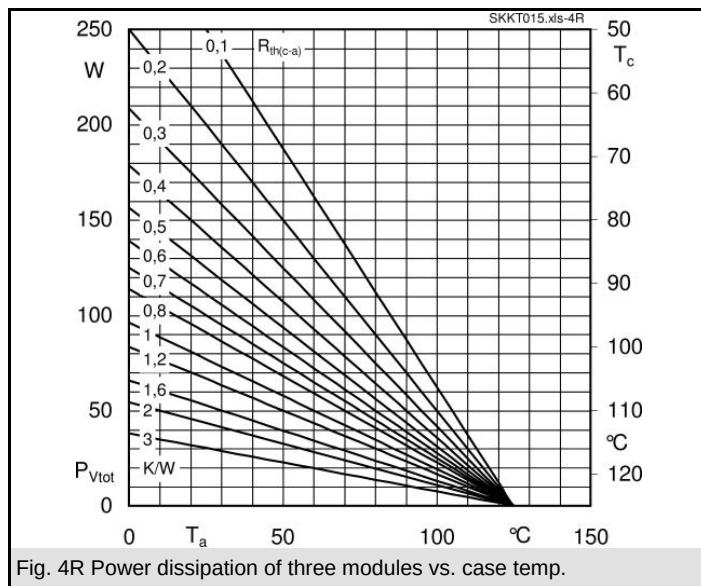
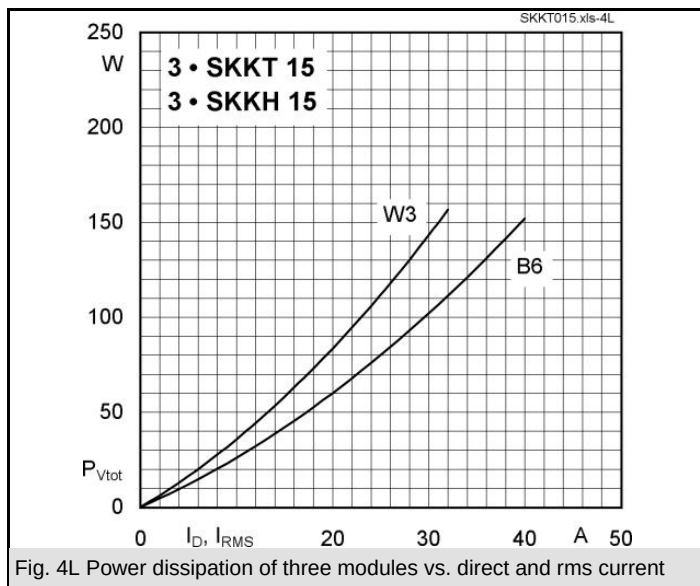


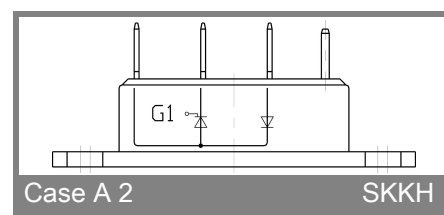
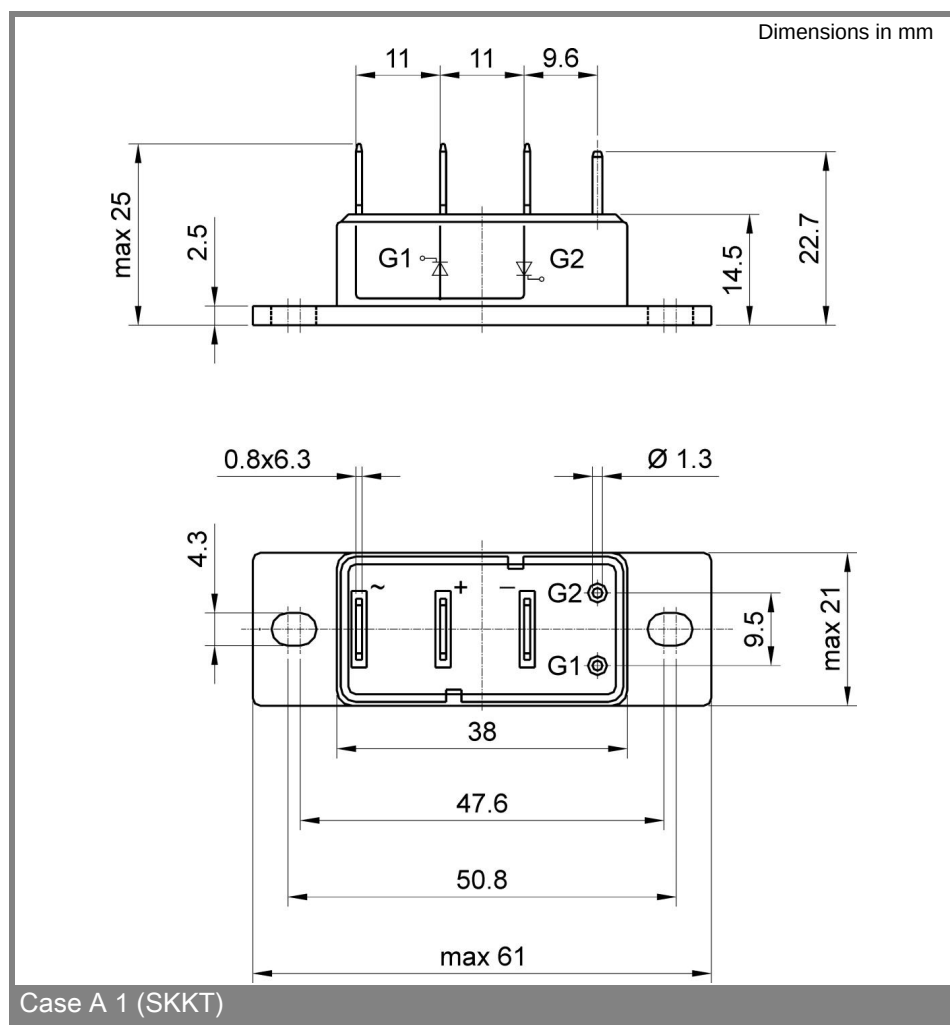
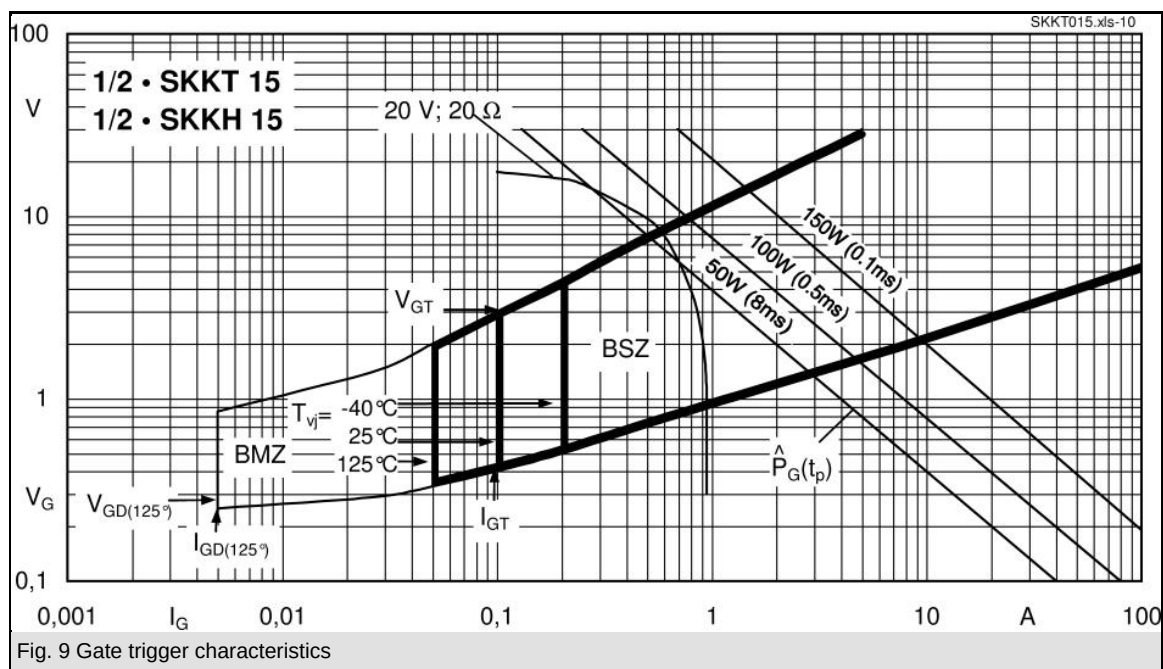
**SKKT**

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